

CSM4800SOP8

30V Dual N-Channel Enhancement Mode MOSFET

Voltage 30 V **Current** 8 A

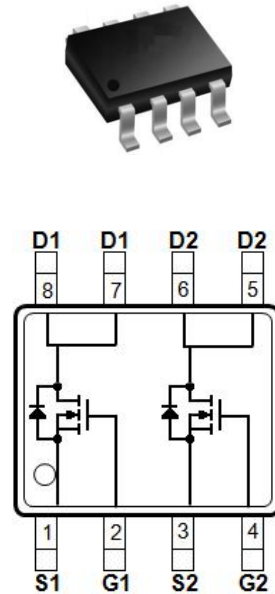
Features

- $R_{DS(ON)}, V_{GS}@10V, I_D@8A < 19m\Omega$
- $R_{DS(ON)}, V_{GS}@4.5V, I_D@5A < 30m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance

Mechanical Data

- Case: SOP-8 package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0029 ounces, 0.083 grams

SOP-8



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V_{GS}	+20	V
Continuous Drain Current	$T_A=25^\circ\text{C}$	I_D	8.0	A
	$T_A=70^\circ\text{C}$		6.0	
Pulsed Drain Current (Note 1)		I_{DM}	32	
Power Dissipation	$T_A=25^\circ\text{C}$	P_D	1.25	W
	$T_A=70^\circ\text{C}$		0.8	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	$^\circ\text{C}$
Typical Thermal Resistance Junction to Ambient (Note 5)		$R_{\theta JA}$	100	$^\circ\text{C/W}$

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1.2	1.7	2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =8A	-	16	19	mΩ
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =5A	-	23	30	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic (Note 6)						
Total Gate Charge	Q _g	V _{DS} =15V, I _D =8A, V _{GS} =4.5V (Note 2,3)	-	4.3	-	nC
Gate-Source Charge	Q _{gs}		-	1.3	-	
Gate-Drain Charge	Q _{gd}		-	1.6	-	
Input Capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	392	-	pF
Output Capacitance	C _{oss}		-	76	-	
Reverse Transfer Capacitance	C _{rss}		-	54	-	
Turn-On Delay Time	t _{d(on)}	V _{DS} =15V, I _D =1A, V _{GS} =10V, R _G =6Ω (Note 2,3)	-	5.9	-	ns
Turn-On Rise Time	t _r		-	11	-	
Turn-Off Delay Time	t _{d(off)}		-	17	-	
Turn-Off Fall Time	t _f		-	3.8	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	8.0	A
Diode Forward Voltage	V _{SD}	I _S =1.0A, V _{GS} =0V	-	0.73	1.0	V

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%
2. Essentially independent of operating temperature typical characteristics.
3. The maximum current rating is package limited.
4. Repetitive rating, pulse width limited by junction temperature T_J(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J = 25°C.
5. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz. square pad of copper.
6. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

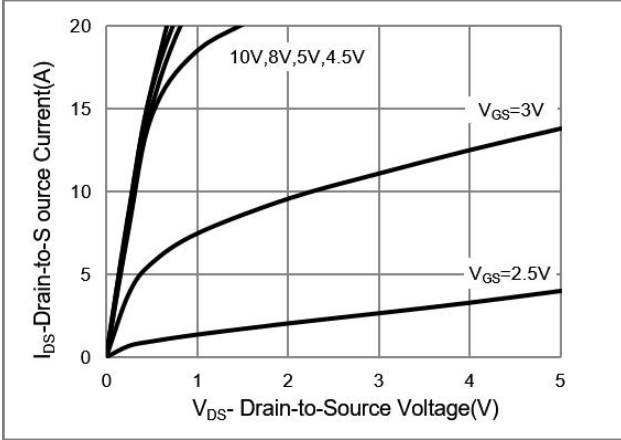


Fig.1 On-Region Characteristics

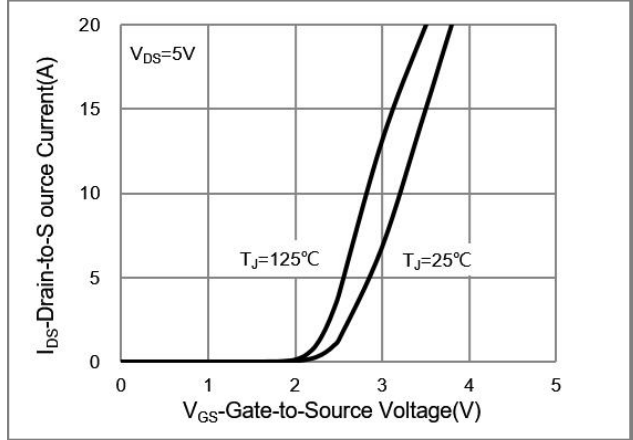


Fig.2 Transfer Characteristics

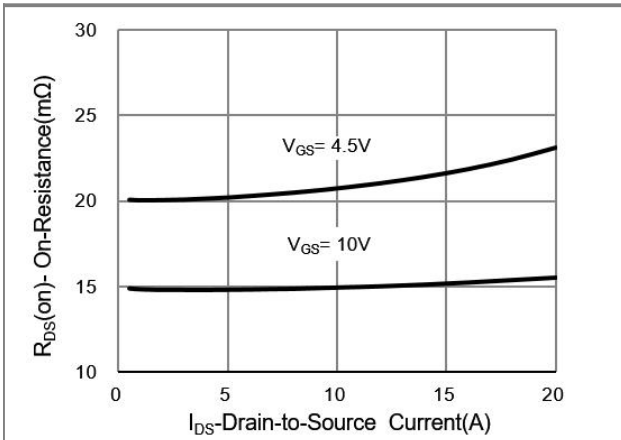


Fig.3 On-Resistance vs. Drain Current

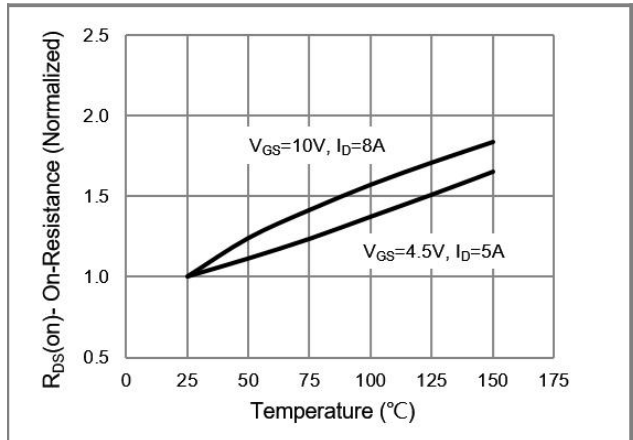


Fig.4 On-Resistance vs. Junction temperature

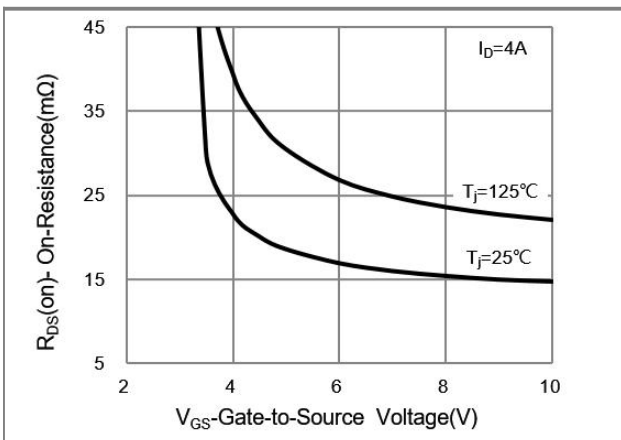


Fig.5 On-Resistance Variation with VGS.

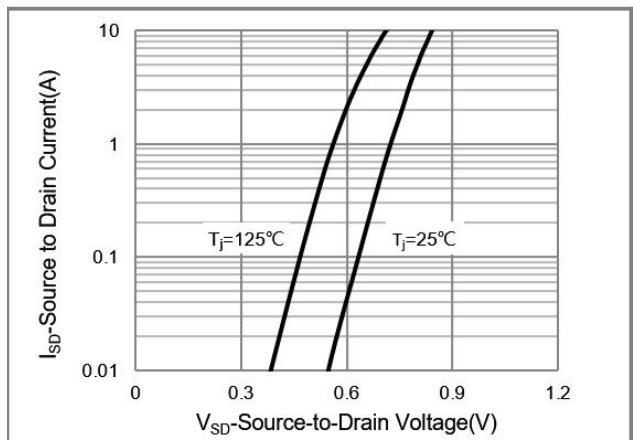


Fig.6 Body Diode Characteristics

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TYPICAL CHARACTERISTIC CURVES

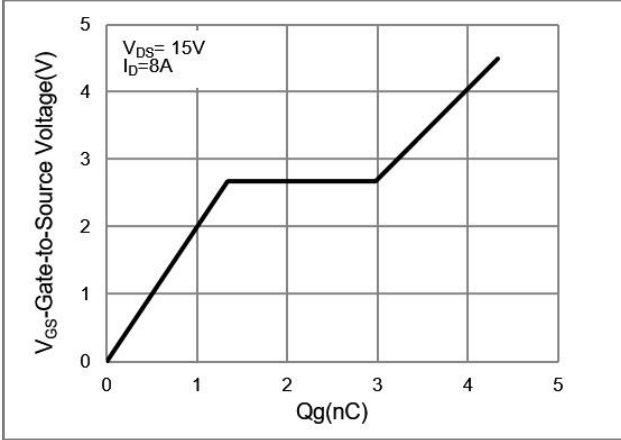


Fig.7 Gate-Charge Characteristics

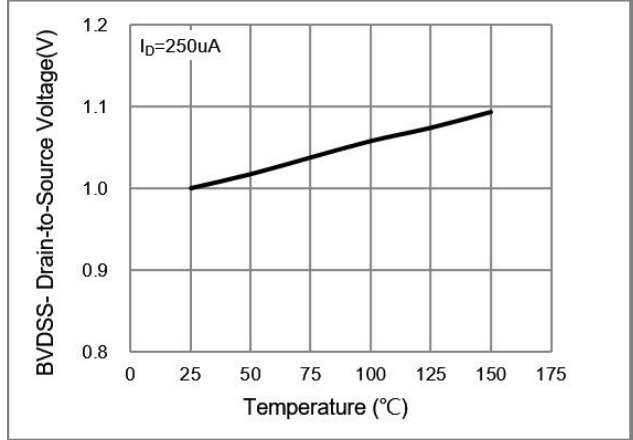


Fig.8 Breakdown Voltage Variation vs. Temperature

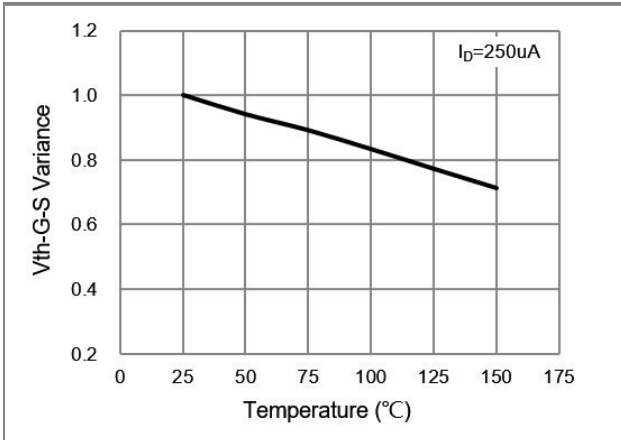


Fig.9 Threshold Voltage Variation with Temperature.

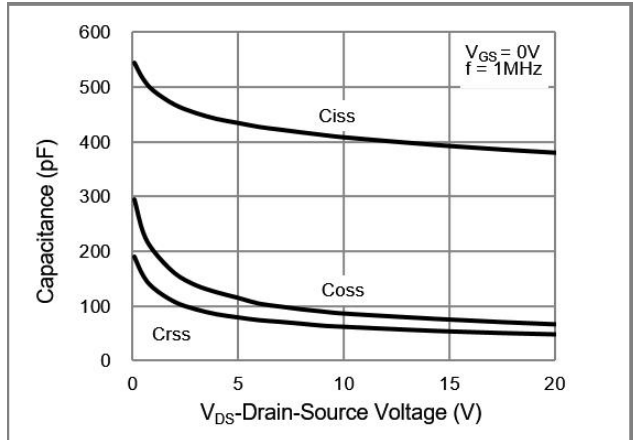


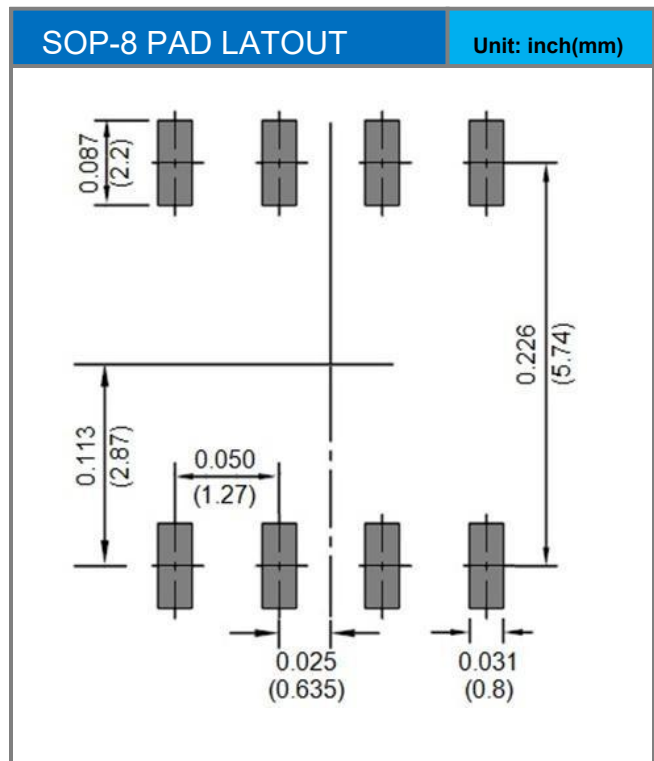
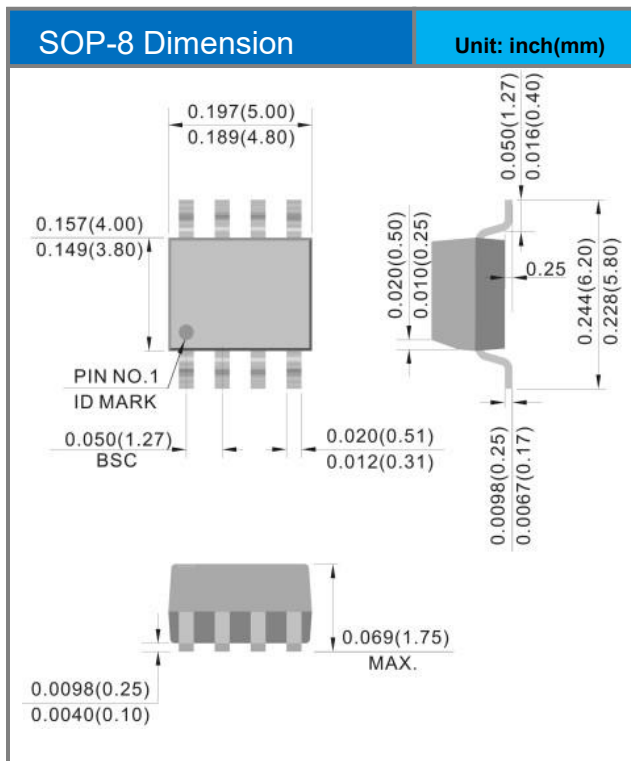
Fig.10 Capacitance vs. Drain-Source Voltage.

CSM4800SOP8

Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type
CSM4800SOP8	SOP-8	3K / reel

Packaging Information & Mounting Pad Layout



CSM4800SOP8

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